AN-1969 LM3424 Boost Evaluation Board

1 Introduction

This evaluation board showcases the LM3424 NFET controller used with a boost current regulator. It is designed to drive 9 to 12 LEDs at a maximum average LED current of 1A from a DC input voltage of 10 to 26V.

The evaluation board showcases many of the LM3424 features including thermal foldback, analog dimming, external switching frequency synchronization, and high frequency PWM dimming, among others. There are many external connection points to facilitate the full evaluation of the LM3424 device including inputs, outputs and test points. Refer to Table 1 for a summary of the connectors and test points.

The boost circuit can be easily redesigned for different specifications by changing only a few components (see Alternate Designs). Note that design modifications can change the system efficiency for better or worse.

This application note is designed to be used in conjunction with the *LM3424 Constant Current N-Channel Controller with Thermal Foldback for Driving LEDs* (SNVS603) data sheet as a reference for the LM3424 boost evaluation board and for a comprehensive explanation of the device, design procedures, and application information.

2 Key Features

- Input: 10V to 26V
- Output: 9 to 12 LEDs at 1A
- Thermal Foldback / Analog Dimming
- PWM Dimming up to 30 kHz
- External Synchronization > 360 kHz
- Input Under-voltage and Output Over-voltage Protection

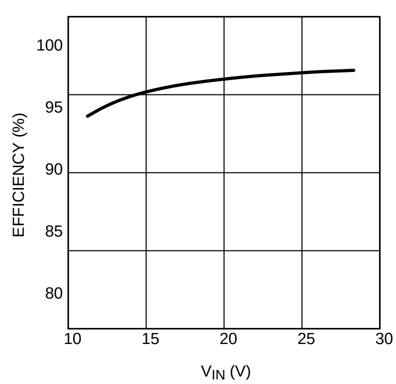

Figure 1. Efficiency with 6 Series LEDS AT 1A

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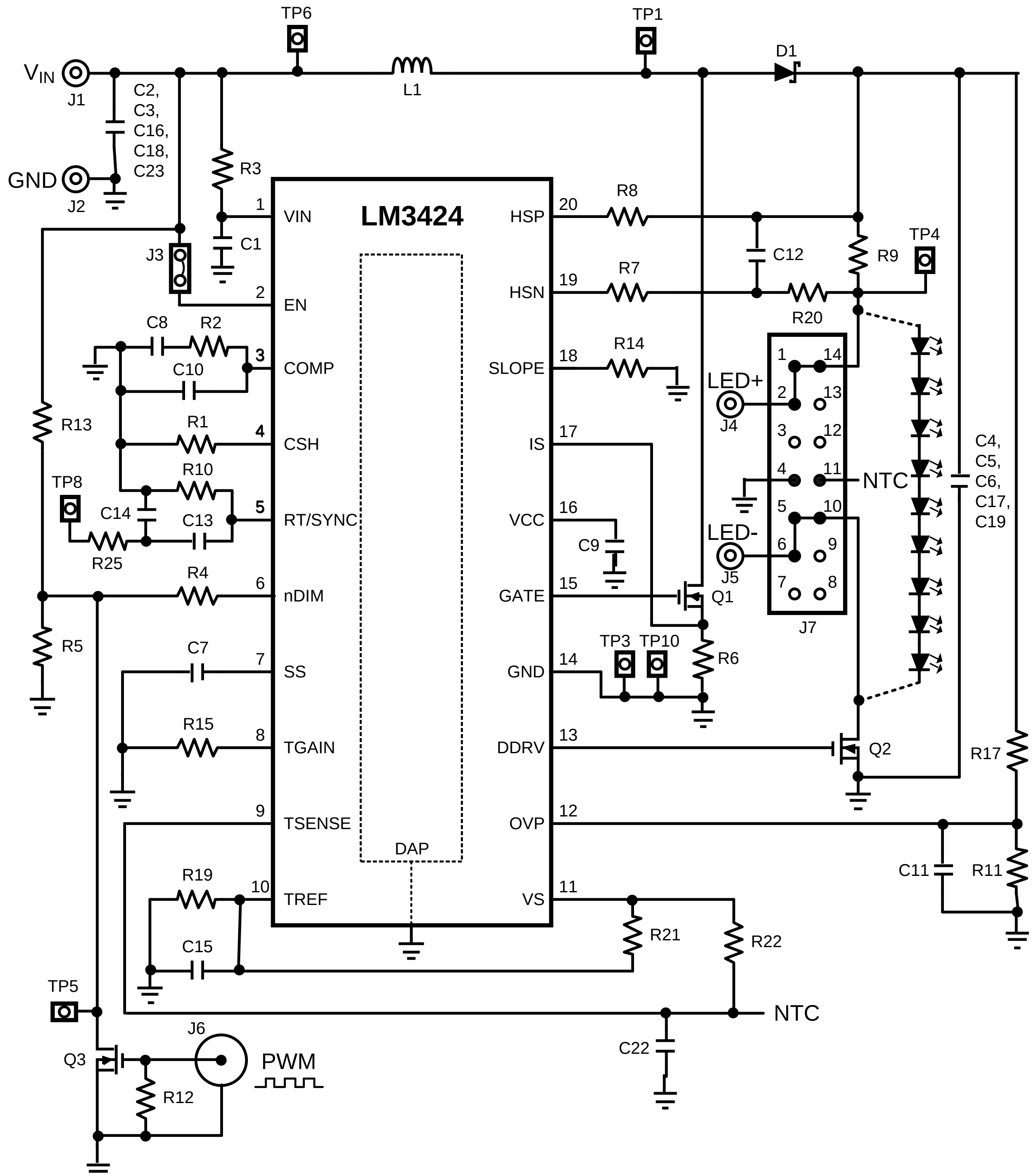
3 External Connection Descriptions

Table 1. Connectors and Test Points

Qty	Name	Description	Application Information
J1	V_{IN}	Input Voltage	Connect to positive terminal of supply voltage.
J2	GND	Input Ground	Connect to negative terminal of supply voltage (GND).
J3	EN	Enable On/Off	Jumper connected enables device.
J4	LED+	LED Positive	Connect to anode (top) of LED string.
J5	LED-	LED Negative	Connect to cathode (bottom) of LED string.
J6	BNC	Dimming Input	Connect a 3V to 10V PWM input signal up to 10 kHz for PWM dimming the LED load.
J7	OUT	Output with NTC	Alternative connector for LED+ and LED-. Pins 4 and 11 are used for connecting an external NTC thermistor. Refer to schematic for detailed connectivity.
TP1	SW	Switch Node Voltage	Test point for switch node (where Q1, D1, and L1 connect).
TP3	SGND	Signal Ground	Connection for GND when applying signals to TP5, TP8, and TP9.
TP4	LED+	LED Positive Voltage	Test point for anode (top) of LED string.
TP5	nDIM	Inverted Dim Signal	Test point for dimming input (inverted from input signal).
TP6	V_{IN}	Input Voltage	Test point for input voltage.
TP8	SYNC	Synchronization Input	Connect a 3V to 6V PWM clock signal > 500 kHz (pulse width of 100ns) to synchronize the LM3424 switching frequency to the external clock.
TP9	NTC	Temp Sense Input	Connect a 0V to 1.24V DC voltage to analog dim the LED current.
TP10	PGND	Power Ground	Test point for GND when monitoring TP1, TP4, or TP6.

4 Schematic



LM3424
VIN
EN
COMP
CSH
RT/SYNC
nDIM
SS
TGAIN
TSENSE
TREF
HSP
HSN
SLOPE
IS
VCC
GATE
GND
DDRV
OVP
VS
DAP
1
2
3
4
5
6
7
8
9
10
20
19
18
17
16
15
14
13
12
11
VIN
J1
GND
J2
C2, C3, C16, C18, C23
TP6
L1
TP1
D1
R3
C1
J3
R13
R5
C8
R2
C10
R1
R10
TP8
C14
C13
R25
R4
C7
R15
R19
C15
TP5
Q3
R12
J6
PWM
R8
R7
R14
C12
R20
R9
TP4
LED+
J4
LED-
J5
J7
NTC
C4, C5, C6, C17, C19
C9
Q1
TP3
TP10
R6
Q2
R17
C11
R11
R21
R22
C22
NTC

5 LM3424 Pin Descriptions

Pin	Name	Description	Application Information
1	V_{IN}	Input Voltage	Bypass with 100 nF capacitor to GND as close to the device as possible in the circuit board layout.
2	EN	Enable	Connect to > 2.4V to enable the device or to < 0.8V for low power shutdown.
3	COMP	Compensation	Connect a capacitor to GND to compensate control loop.
4	CSH	Current Sense High	Connect a resistor to GND to set the signal current. Can also be used to analog dim as explained in the *Thermal Foldback / Analog Dimming* section of the datasheet.
5	RT	Resistor Timing	Connect a resistor to GND to set the switching frequency. Can also be used to synchronize external clock as explained in the *Switching Frequency* section of the datasheet.
6	nDIM	Not DIM input	Connect a PWM signal for dimming as detailed in the *PWM Dimming* section of the datasheet and/or a resistor divider from V_{IN} to program input under-voltage lockout (UVLO). Turn-on threshold is 1.24V and hysteresis for turn-off is provided by 20 µA current source.
7	SS	Soft-start	Connect a capacitor to GND to extend start-up time.
8	TGAIN	Temperature Foldback Gain	Connect a resistor to GND to set the foldback slope.
9	TSENSE	Temperature Sense Input	Connect a resistor/ thermistor divider from V_S to sense the temperature as explained in the *Thermal Foldback / Analog Dimming* section of the datasheet.
10	TREF	Temperature Foldback Reference	Connect a resistor divider from V_S to set the temperature foldback reference voltage.
11	V_S	Voltage Reference	2.45V reference for temperature foldback circuit and other external circuitry.
12	OVP	Over-Voltage Protection	Connect to a resistor divider from V_O to program output over-voltage lockout (OVLO). Turn-off threshold is 1.24V and hysteresis for turn-on is provided by 20 µA current source.
13	DDRV	Dimming Gate Drive Output	Connect to gate of dimming MosFET.
14	GND	Ground	Connect to DAP to provide proper system GND
15	GATE	Gate Drive Output	Connect to gate of main switching MosFET.
16	V_{CC}	Internal Regulator Output	Bypass with a 2.2 µF–3.3 µF, ceramic capacitor to GND.
17	IS	Main Switch Current Sense	Connect to the drain of the main N-channel MosFET switch for R_{DS-ON} sensing or to a sense resistor installed in the source of the same device.
18	SLOPE	Slope Compensation	Connect a resistor to GND to set slope of additional ramp.
19	HSN	High-Side LED Current Sense Negative	Connect through a series resistor to the negative side of the LED current sense resistor.
20	HSP	High-Side LED Current Sense Positive	Connect through a series resistor to the positive side of the LED current sense resistor.
DAP (21)	DAP	Thermal pad on bottom of IC	Connect to GND and place 6 - 9 vias to bottom layer ground pour.

6 Bill of Materials

Qty	Part ID	Part Value	Manufacturer	Part Number
3	C1, C5, C23	0.1 µF X7R 10% 100V	TDK	C2012X7R2A104K
4	C2, C3, C16, C18	6.8 µF X7R 10% 50V	TDK	C5750X7R1H685K
4	C4, C6, C17, C19	10 µF X7R 10% 50V	TDK	C5750X7R1H106K
2	C7, C22	0.47 µF X7R 10% 16V	MURATA	GRM21BR71C474KA01L
0	C8	DNP		
1	C9	2.2 µF X7R 10% 16V	MURATA	GRM21BR71C225KA12L
1	C10	1 µF X7R 10% 16V	MURATA	GRM21BR71C105KA01L
1	C11	47 pF COG/NPO 5% 50V	AVX	08055A470JAT2A
1	C12	0.22 µF X7R 10% 16V	MURATA	GRM219R71C224KA01D
2	C13, C14	100 pF COG/NPO 5% 50V	MURATA	GRM2165C1H101JA01D
1	C15	1 µF X7R 10% 16V	MURATA	GRM21BR71C105MA01L
1	D1	Schottky 100V 12A	VISHAY	12CWQ10FNPBF
4	J1, J2, J4, J5	Banana Jack	KEYSTONE	575-8
1	J3	1x2 Header Male	SAMTEC	TSW-102-07-T-S
1	J6	BNC connector	AMPHENOL	112536
1	J7	2x7 Header Male Shrouded RA	SAMTEC	TSSH-107-01-SDRA
1	L1	33 µH 20% 6.3A	COILCRAFT	MSS1278-333MLB
2	Q1, Q2	NMOS 100V 32A	FAIRCHILD	FDD3682
1	Q3	NMOS 60V 260mA	ON-SEMI	2N7002ET1G
2	R1, R11	12.4 kΩ 1%	VISHAY	CRCW080512K4FKEA
0	R2	DNP		
2	R3, R20	10Ω 1%	VISHAY	CRCW080510R0FKEA
1	R4	17.4 kΩ 1%	VISHAY	CRCW080517K4FKEA
1	R5	1.43 kΩ 1%	VISHAY	CRCW08051K43FKEA
1	R6	0.04Ω 1% 1W	VISHAY	WSL2512R0400FEA
2	R7, R8	1.0 kΩ 1%	VISHAY	CRCW08051K00FKEA
1	R9	0.1Ω 1% 1W	VISHAY	WSL2512R1000FEA
1	R10	20.0 kΩ 1%	VISHAY	CRCW080520K0FKEA
4	R12, R13, R14, R15	10.0 kΩ 1%	VISHAY	CRCW080510K0FKEA
1	R17	499 kΩ 1%	VISHAY	CRCW0805499KFKEA
3	R19, R21, R22	49.9 kΩ 1%	VISHAY	CRCW080549K9FKEA
1	R25	150Ω 1%	VISHAY	CRCW0805150RFKEA
8	TP1, TP3, TP4, TP5, TP6, TP8, TP9, TP10	Turret	Keystone	1502-2
1	U1	Boost controller	NSC	LM3424MH

7 PCB Layout

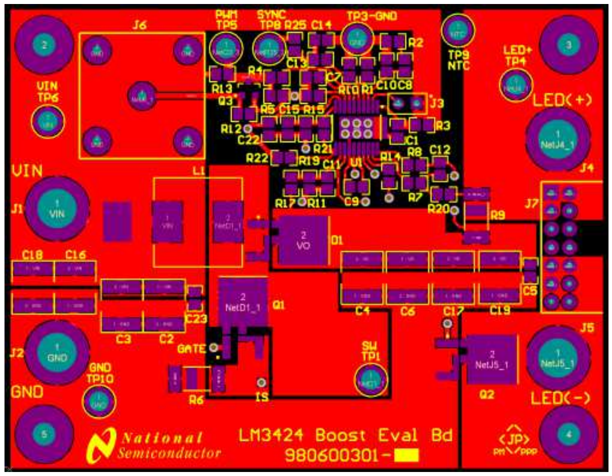


Figure 2. Top Layer

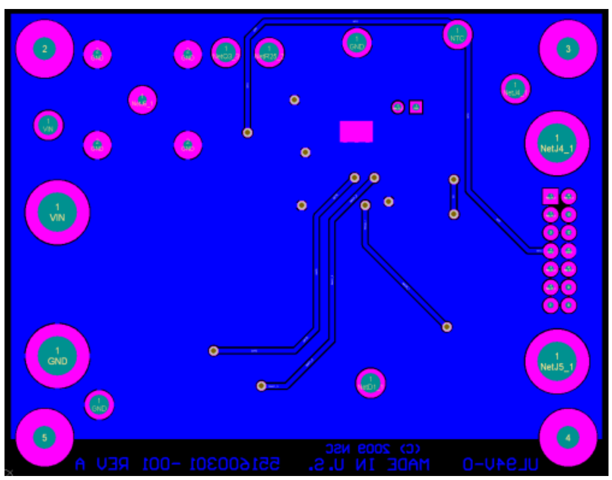


Figure 3. Bottom Layer

8 Design Procedure

8.1 Specifications

$N = 6$

$V_{LED} = 3.5V$

$r_{LED} = 325\ m\Omega$

$V_{IN} = 24V$

$V_{IN\text{-}MIN} = 10V$

$V_{IN\text{-}MAX} = 70V$

$f_{SW} = 500\ kHz$

$V_{SNS} = 100\ mV$

$I_{LED} = 1A$

$\Delta i_{L\text{-}PP} = 700\ mA$

$\Delta i_{LED\text{-}PP} = 12\ mA$

$\Delta v_{IN\text{-}PP} = 100\ mV$

$I_{LIM} = 6A$

$V_{TURN\text{-}ON} = 10V$

$V_{HYS} = 3V$

$V_{TURN\text{-}OFF} = 40V$

$V_{HYSO} = 10V$

$T_{BK} = 70°C$

$T_{END} = 120°C$

$t_{TSU} = 30\ ms$

8.2 Operating Point

Solve for V_O and r_D:

$$V_O = N \times V_{LED} = 9 \times 3.5V = 31.5V \quad (1)$$

$$r_D = N \times r_{LED} = 9 \times 325\ m\Omega = 2.925\Omega \quad (2)$$

Solve for D, D', D_{MAX}, and D_{MIN}:

$$D = \frac{V_O - V_{IN}}{V_O} = \frac{31.5V - 24V}{31.5V} = 0.238 \quad (3)$$

$$D' = 1 - D = 1 - 0.238 = 0.762 \quad (4)$$

$$D_{MIN} = \frac{V_O - V_{IN\text{-}MAX}}{V_O} = \frac{31.5V - 26V}{31.5V} = 0.175 \quad (5)$$

$$D_{MAX} = \frac{V_O - V_{IN\text{-}MIN}}{V_O} = \frac{31.5V - 10V}{31.5V} = 0.683 \quad (6)$$

8.3 Switching Frequency

Solve for R_T:

$$R10 = \frac{1 + 1.95e^{-8} \times f_{SW}}{1.40e^{-10} \times f_{SW}} = \frac{1 + 1.95e^{-8} \times 360\ kHz}{1.40e^{-10} \times 360\ kHz} = 19.99\ k\Omega \quad (7)$$

The closest standard resistor is 14.3 kΩ therefore f_{SW} is:

$$f_{SW} = \frac{1}{1.40e^{-10} \times R10 - 1.95e^{-8}}$$

$$f_{SW} = \frac{1}{1.40e^{-10} \times 20.0\ k\Omega - 1.95e^{-8}} = 360\ kHz \tag{8}$$

The chosen component from step 2 is:

$$\boxed{R10 = 20\ k\Omega} \tag{9}$$

8.4 Average LED Current

Solve for R_{SNS}:

$$R9 = \frac{V_{SNS}}{I_{LED}} = \frac{100\ mV}{1A} = 0.1\Omega \tag{10}$$

Assume R_{CSH} = 12.4 kΩ and solve for R_{HSP}:

$$R8 = \frac{I_{LED} \times R1 \times R9}{1.24V} = \frac{1A \times 1.24\ k\Omega \times 0.1\Omega}{1.24V} = 1.0\ k\Omega \tag{11}$$

The closest standard resistor for R_{SNS} is actually 0.1Ω and for R_{HSP} is actually 1 kΩ therefore I_{LED} is:

$$I_{LED} = \frac{1.24V \times R8}{R9 \times R1} = \frac{1.24V \times 1.0\ k\Omega}{0.1\Omega \times 1.24\ k\Omega} = 1.0A \tag{12}$$

The chosen components from step 3 are:

$$\boxed{\begin{array}{l} R9 = 0.1\Omega \\ R1 = 12.4\ k\Omega \\ R8 = R7 = 1\ k\Omega \end{array}} \tag{13}$$

8.5 Thermal Foldback

Using a standard 100k NTC thermistor (connected to pins 4 and ll), find the resistances corresponding to T_{BK} and T_{END} ($R_{NTC\text{-}BK}$ = 243 kΩ and $R_{NTC\text{-}END}$ = 71.5 kΩ) from the manufacturer's datasheet. Assuming R_{REF1} = R_{REF2} = 49.9 kΩ, then R_{BIAS} = $R_{NTC\text{-}BK}$= 243 kΩ.

Solve for R_{GAIN}:

$$R_{GAIN} = \frac{\left(\frac{R_{REF1}}{R_{REF1} + R_{REF2}} - \frac{R_{NTC\text{-}END}}{R_{NTC\text{-}END} + R_{BIAS}}\right) \times 2.45V}{I_{CSH}}$$

$$R_{GAIN} = \frac{\left(\frac{1}{2} - \frac{71.5\ k\Omega}{71.5\ k\Omega + 243\ k\Omega}\right) \times 2.45V}{100\ \mu A} = 6.68\ k\Omega \tag{14}$$

The chosen components from step 4 are:

$$\boxed{\begin{array}{l} R_{GAIN} = 6.81\ k\Omega \\ R_{BIAS} = 243\ k\Omega \\ R_{REF1} = R_{REF2} = 49.9\ k\Omega \end{array}} \tag{15}$$

8.6 Inductor Ripple Current

Solve for L1:

$$L1 = \frac{V_{IN} \times D}{\Delta i_{L\text{-}PP} \times f_{SW}} = \frac{24V \times 0.238}{500\ mA \times 360\ kHz} = 31.7\ \mu H \tag{16}$$

The closest standard inductor is 33 µH therefore $\Delta i_{L\text{-}PP}$ is:

$$\Delta i_{L\text{-}PP} = \frac{V_{IN} \times D}{L1 \times f_{SW}} = \frac{24V \times 0.238}{33\ \mu H \times 360\ kHz} = 481\ mA \quad (17)$$

Determine minimum allowable RMS current rating:

$$I_{L\text{-}RMS} = \frac{I_{LED}}{D'} \times \sqrt{1 + \frac{1}{12} \times \left(\frac{\Delta I_{L\text{-}PP} \times D'}{I_{LED}}\right)^2}$$

$$I_{L\text{-}RMS} = \frac{1A}{0.762} \times \sqrt{1 + \frac{1}{12} \times \left(\frac{481\ mA \times 0.762}{1A}\right)^2} = 1.32A \quad (18)$$

The chosen component from step 5 is:

$$\boxed{L1 = 33\ \mu H} \quad (19)$$

8.7 Output Capacitance

Solve for C_O:

$$C_O = \frac{I_{LED} \times D}{r_D \times \Delta i_{LED\text{-}PP} \times f_{SW}}$$

$$C_O = \frac{1A \times 0.238}{2.925\Omega \times 6\ mA \times 360\ kHz} = 38\ \mu F \quad (20)$$

The closest capacitance totals 40 µF therefore $\Delta i_{LED\text{-}PP}$ is:

$$\Delta i_{LED\text{-}PP} = \frac{I_{LED} \times D}{r_D \times C_O \times f_{SW}}$$

$$\Delta i_{LED\text{-}PP} = \frac{1A \times 0.238}{2.925\Omega \times 40\ \mu F \times 360\ kHz} = 5.7\ mA \quad (21)$$

Determine minimum allowable RMS current rating:

$$I_{CO\text{-}RMS} = I_{LED} \times \sqrt{\frac{D_{MAX}}{1 - D_{MAX}}} = 1A \times \sqrt{\frac{0.683}{1 - 0.683}} = 1.47A \quad (22)$$

The chosen components from step 6 are:

$$\boxed{C4 = C6 = C17 = C19 = 10\ \mu F} \quad (23)$$

8.8 Peak Current Limit

Solve for R_{LIM}:

$$R6 = \frac{245\ mV}{I_{LIM}} = \frac{245\ mV}{6A} = 0.041\Omega \quad (24)$$

The closest standard resistor is 0.04 Ω therefore I_{LIM} is:

$$I_{LIM} = \frac{245\ mV}{R6} = \frac{245\ mV}{0.04\Omega} = 6.13A \quad (25)$$

The chosen component from step 7 is:

$$\boxed{R6 = 0.04\Omega} \quad (26)$$

8.9 Slope Compensation

Solve for R_{SLP}:

$$R_{SLP} = \frac{1.5e^{13} \times L1}{V_O \times R_T \times R_{SNS}}$$

$$R_{SLP} = \frac{1.5e^{13} \times 33\,\mu H}{21V \times 14.3\,k\Omega \times 0.1\Omega} = 16.5\,k\Omega \quad (27)$$

The chosen component from step 8 is:

$$\boxed{R_{SLP} = 16.5\,k\Omega} \quad (28)$$

8.10 Loop Compensation

ω_{P1} is approximated:

$$\omega_{P1} = \frac{2}{r_D \times C_O} = \frac{2}{2.925\Omega \times 40\,\mu F} = 17\,k\frac{rad}{sec} \quad (29)$$

ω_{Z1} is approximated:

$$\omega_{Z1} = \frac{r_D \times D'^2}{L1} = \frac{2.925\Omega \times 0.762^2}{33\,\mu H} = 52\,k\frac{rad}{sec} \quad (30)$$

T_{U0} is approximated:

$$T_{U0} = \frac{D' \times 310V}{I_{LED} \times R6} = \frac{0.762 \times 310V}{1A \times 0.04\Omega} = 5900 \quad (31)$$

To ensure stability, calculate ω_{P2}:

$$\omega_{P2} = \frac{\min(\omega_{P1}, \omega_{Z1})}{5 \times T_{U0}} = \frac{\omega_{P1}}{5 \times 5900} = \frac{17k\frac{rad}{sec}}{5 \times 5900} = 0.58\frac{rad}{sec} \quad (32)$$

Solve for C_{CMP}:

$$C10 = \frac{1}{\omega_{P2} \times 5e^6\Omega} = \frac{1}{0.58\frac{rad}{sec} \times 5e^6\Omega} = 0.35\,\mu F \quad (33)$$

To attenuate switching noise, calculate ω_{P3}:

$$\omega_{P3} = (\max\omega_{P1}, \omega_{Z1}) \times 10 = \omega_{Z1} \times 10$$

$$\omega_{P3} = 52k\frac{rad}{sec} \times 10 = 520k\frac{rad}{sec} \quad (34)$$

Assume $R_{FS} = 10\Omega$ and solve for C_{FS}:

$$C12 = \frac{1}{10\Omega \times \omega_{P3}} = \frac{1}{10\Omega \times 520k\frac{rad}{sec}} = 0.19\,\mu F \quad (35)$$

The chosen components from step 9 are:

$$\boxed{\begin{array}{l} C10 = 1\,\mu F \\ R20 = 10\Omega \\ C12 = 0.22\,\mu F \end{array}} \quad (36)$$

8.11 Input Capacitance

Solve for the minimum C_{IN}:

$$C_{IN} = \frac{\Delta i_{L-PP}}{8 \times \Delta v_{IN-PP} \times f_{SW}} = \frac{481\,mA}{8 \times 50\,mV \times 360\,kHz} = 3.4\,\mu F \quad (37)$$

To minimize power supply interaction a 200% larger capacitance of approximately 20 µF is used, therefore the actual Δv_{IN-PP} is much lower. Since high voltage ceramic capacitor selection is limited, four 4.7 µF X7R capacitors are chosen.

Determine minimum allowable RMS current rating:

$$I_{IN\text{-}RMS} = \frac{\Delta i_{L\text{-}PP}}{\sqrt{12}} = \frac{481\text{ mA}}{\sqrt{12}} = 139\text{ mA} \quad (38)$$

The chosen components from step 10 are:

$$\boxed{C2 = C3 = C16 = C18 = 6.8\ \mu F} \quad (39)$$

8.12 NFET

Determine minimum Q1 voltage rating and current rating:

$$V_{T\text{-}MAX} = V_O = 31.5V \quad (40)$$

$$I_{T\text{-}MAX} = \frac{0.683}{1 - 0.683} \times 1A = 2.2A \quad (41)$$

A 100V NFET is chosen with a current rating of 32A due to the low $R_{DS\text{-}ON}$ = 50 mΩ. Determine $I_{T\text{-}RMS}$ and P_T:

$$I_{T\text{-}RMS} = \frac{I_{LED}}{D'} \times \sqrt{D} = \frac{1A}{0.762} \times \sqrt{0.238} = 640\text{ mA} \quad (42)$$

$$P_T = I_{T\text{-}RMS}^2 \times R_{DSON} = 640\text{ mA}^2 \times 50\text{ m}\Omega = 20\text{ mW} \quad (43)$$

The chosen component from step 11 is:

$$\boxed{Q1 \rightarrow 32A,\ 100V,\ DPAK} \quad (44)$$

8.13 Diode

Determine minimum D1 voltage rating and current rating:

$$V_{RD\text{-}MAX} = V_O = 31.5V \quad (45)$$

$$I_{D\text{-}MAX} = I_{LED} = 1A \quad (46)$$

A 100V diode is chosen with a current rating of 12A and V_D = 600 mV. Determine P_D:

$$P_D = I_D \times V_{FD} = 1A \times 600\text{ mV} = 600\text{ mW} \quad (47)$$

The chosen component from step 12 is:

$$\boxed{D1 \rightarrow 12A,\ 100V,\ DPAK} \quad (48)$$

8.14 Input UVLO

Solve for R_{UV2}:

$$R4 = \frac{R5 \times (V_{HYS} - 20\ \mu A \times R13)}{20\ \mu A \times (R5 + R13)}$$

$$R4 = \frac{1.43\text{ k}\Omega \times (3V - 20\ \mu A \times 10\text{ k}\Omega)}{20\ \mu A \times (1.43\text{ k}\Omega + 10\text{ k}\Omega)} = 17.5\text{ k}\Omega \quad (49)$$

The closest standard resistor is 150 kΩ therefore V_{HYS} is:

$$V_{HYS} = \frac{20\ \mu A \times R4 \times (R5 + R13)}{R5} + 20\ \mu A \times R13$$

$$V_{HYS} = \frac{20\ \mu A \times 17.4\text{ k}\Omega \times (1.43\text{ k}\Omega + 10\text{ k}\Omega)}{1.43\text{ k}\Omega} + 20\ \mu A \times 10\text{ k}\Omega = 2.98V \quad (50)$$

Solve for R_{UV1}:

$$R5 = \frac{1.24V \times R13}{V_{TURN\text{-}ON} - 1.24V} = \frac{1.24V \times 10\ k\Omega}{10V - 1.24V} = 1.42\ k\Omega \quad (51)$$

The closest standard resistor is 21 kΩ making $V_{TURN\text{-}ON}$:

$$V_{TURN\text{-}ON} = \frac{1.24V \times (R5 + R13)}{R5}$$

$$V_{TURN\text{-}ON} = \frac{1.24V \times (1.43\ k\Omega + 10\ k\Omega)}{1.43\ k\Omega} = 9.91V \quad (52)$$

The chosen components from step 13 are:

$$\boxed{\begin{array}{l} R5 = 1.43\ k\Omega \\ R13 = 10\ k\Omega \\ R4 = 17.4\ k\Omega \end{array}} \quad (53)$$

8.15 Output OVLO

Solve for R_{OV2}:

$$R17 = \frac{V_{HYSO}}{20\ \mu A} = \frac{10V}{20\ \mu A} = 500\ k\Omega \quad (54)$$

The closest standard resistor is 499 kΩ therefore V_{HYSO} is:

$$V_{HYSO} = R17 \times 20\ \mu A = 499\ k\Omega \times 20\ \mu A = 9.98V \quad (55)$$

Solve for R_{OV1}:

$$R11 = \frac{1.24V \times R17}{V_{TURN\text{-}OFF} - 1.24V} = \frac{1.24V \times 499\ k\Omega}{50V - 620\ mV} = 12.5\ k\Omega \quad (56)$$

The closest standard resistor is 15.8 kΩ making $V_{TURN\text{-}OFF}$:

$$V_{TURN\text{-}OFF} = \frac{1.24V \times (R11 + R17)}{R11}$$

$$V_{TURN\text{-}OFF} = \frac{1.24V \times (12.4\ k\Omega + 499\ k\Omega)}{12.4\ k\Omega} = 51.1V \quad (57)$$

The chosen components from step 14 are:

$$\boxed{\begin{array}{l} R11 = 12.4\ k\Omega \\ R17 = 499\ k\Omega \end{array}} \quad (58)$$

8.16 Soft-Start

Solve for t_{SU}:

$$t_{SU} = 168\Omega \times C_{BYP} + 36\ k\Omega \times C_{CMP} + \frac{V_O}{I_{LED}} \times C_O$$

$$t_{SU} = 168\Omega \times 2.2\ \mu F + 36\ k\Omega \times 0.33\ \mu F + \frac{21V}{1A} \times 40\ \mu F$$

$$t_{SU} = 13.1\ ms \quad (59)$$

If t_{SU} is less than t_{TSU}, solve for $t_{SU\text{-}SS\text{-}BASE}$:

$$t_{SU\text{-}SS\text{-}BASE} = 168\Omega \times C_{BYP} + 28\ k\Omega \times C_{CMP} + \frac{V_O}{I_{LED}} \times C_O$$

$$t_{SU-SS-BASE} = 168\Omega \times 2.2\ \mu F + 28\ k\Omega \times 0.33\ \mu F + \frac{21V}{1A} \times 40\ \mu F$$

$$t_{SU-SS-BASE} = 10.5\ ms \quad (60)$$

Solve for C_{SS}:

$$C_{SS} = \frac{(t_{TSU} - t_{SU\text{-}SS\text{-}BASE})}{20\ k\Omega} = \frac{(30\ ms - 10.5\ ms)}{20\ k\Omega} = 975\ nF \tag{61}$$

The chosen component from step 15 is:

$$\boxed{C_{SS} = 1\ \mu F} \tag{62}$$

9 Typical Waveforms

T_A = +25°C, V_{IN} = 24V and V_O = 32V.

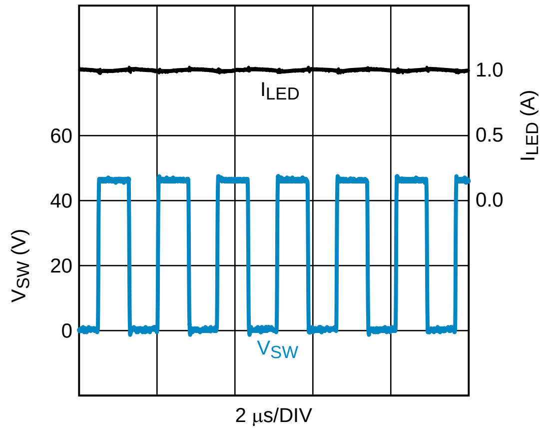


Figure 4. STANDARD OPERATION TP1 switch node voltage (V_{SW}) LED current (I_{LED})

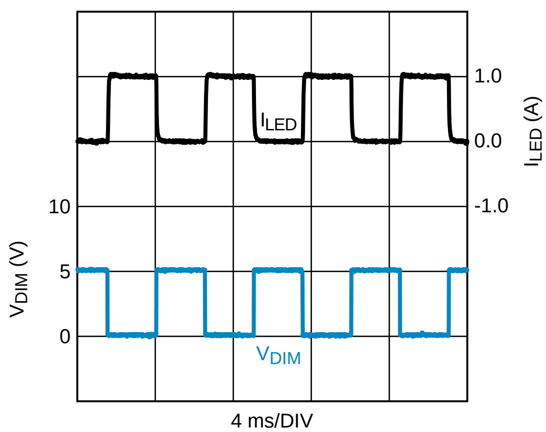


Figure 5. 200Hz 50% PWM DIMMING TP5 dim voltage (V_{DIM}) LED current (I_{LED})

10 Alternate Designs

Alternate designs with the LM3429 evaluation board are possible with very few changes to the existing hardware. The evaluation board FETs and diodes are already rated higher than necessary for design flexibility. The input UVLO, output OVP, input and output capacitance can remain the same for the designs shown below. These alternate designs can be evaluated by changing only R9, R10, and L1.

Table 2 gives the main specifications for four different designs and the corresponding values for R9, R10, and L1. PWM dimming can be evaluated with any of these designs.

Table 2. Alternate Design Specifications

Specification / Component	Design 1	Design 2	Design 3	Design 4
V_{IN}	10V	15V	20V	25V
V_O	14V	21V	28V	35V
f_{SW}	600kHz	700kHz	500kHz	700kHz
I_{LED}	2A	500mA	2.5A	1.25A
R9	0.05Ω	0.2Ω	0.04Ω	0.08Ω
R10	12.1 kΩ	10.2 kΩ	14.3 kΩ	10.2 kΩ
L1	22µH	68µH	15µH	33µH